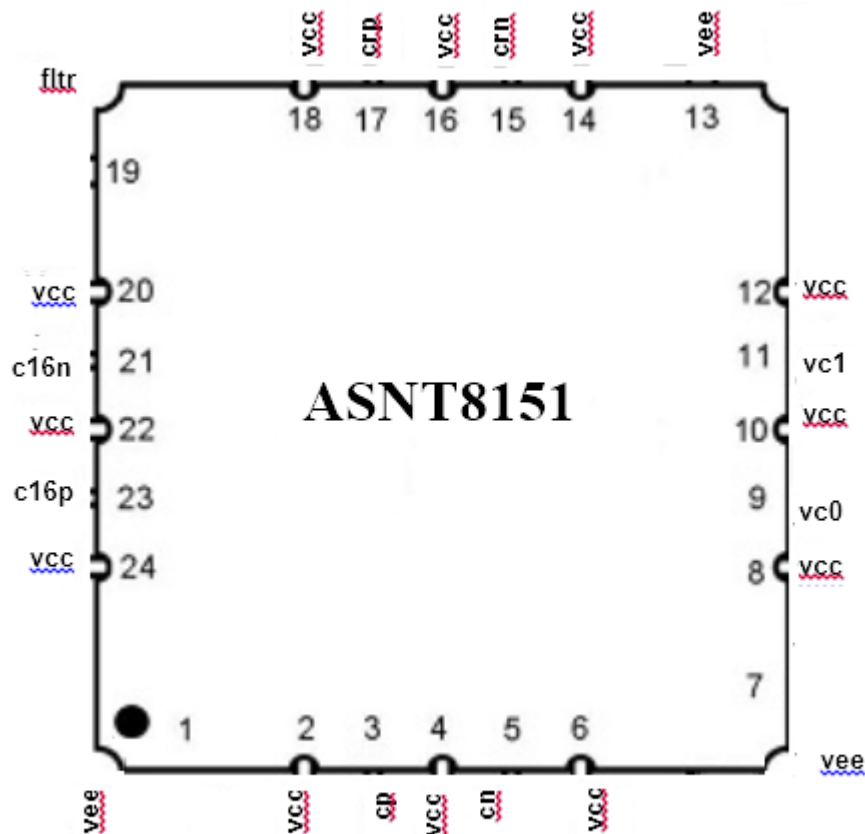


ASNT8151-KHC

24.0-to-32.1GHz Programmable PLL with 3 integrated VCOs

- Programmable clock multiplier (CMU) with three selectable frequency ranges of internal PLL
- External RC loop filter
- LVDS input reference clock interface
- Fully differential CML output full-rate clock interface
- Selectable LVDS output clock divided-by-16 interface
- 3-state input control interface
- Single positive or negative power supply
- Power consumption: 0.53W at the maximum operational speed
- Fabricated in SiGe for high performance, yield, and reliability
- Custom CQFN 24-pin package



DESCRIPTION

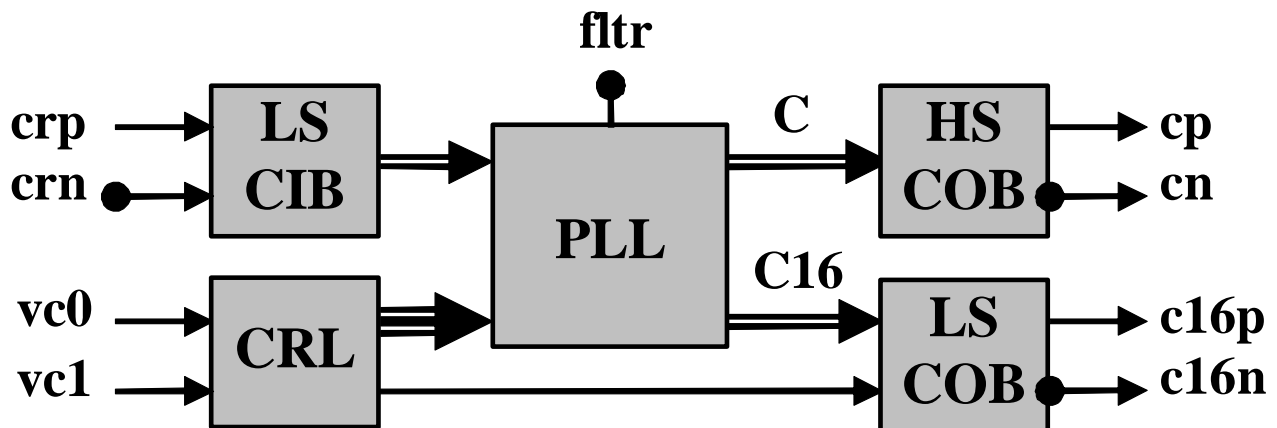


Fig. 1. Functional Block Diagram

The ASNT8151-KHC is a clock multiplication unit (CMU) with a triple-range phase-locked loop (PLL) incorporating three high-speed voltage-controlled oscillators: VCO1 (lower frequency), VCO2 (medium frequency), and VCO3 (higher frequency). The chip shown in Fig. 1 generates a high-speed clock signal **cp/cn** with its phase and frequency locked to those of the incoming reference clock **crp/crn**. The differential clock **cp/cn** with frequency f is delivered to the output by CML output buffer **HS COB**. The reference clock **crp/crn** with frequency $f/16$ is accepted by LVDS input buffer **LS CIB**. The chip also generates a divided-by-16 clock signal **c16p/c16n** with frequency $f/16$ that is delivered to the output by LVDS output buffer **LS COB**. One of the VCOs is activated using two 3-state control signals **vc0** and **vc1**. The same control signals are used to activate or disable the output buffer **LS COB**.

When operating in closed-loop mode, the PLL requires an external loop filter connected to pin **fltr**. The PLL also supports an open-loop mode of operation with its selected VCO controlled externally by a voltage applied to the filter pin **fltr**.

The part's high-speed output buffer supports the CML logic interface with on chip 50Ω termination to **vcc** and may be used differentially, AC/DC coupled, single-ended, or in any combination. The part's low-speed I/Os support the LVDS interface with internal 100Ω termination between the direct and inverted lines. The differential DC signaling mode is recommended for optimal performance.

LS CIB

The Low-Speed Clock Input Buffer (LS CIB) can process an external reference clock signal **crp/crn** with a frequency equal to $1/16$ of the selected VCO frequency. The clock inputs support the LVDS logic interface with on chip 100Ω termination between the direct and inverted lines. The proprietary LVDS buffer exceeds the requirements of standards IEEE Std. 1596.3-1996 and ANSI/TIA/EIA-644-1995.

It is designed to accept a differential signal with a wide range of DC common mode voltages, or a single-ended (SE) signal applied to one input pin with a DC threshold voltage applied to the other input pin. In case of a SE AC-terminated input, the common mode voltage should satisfy the requirements presented in ELECTRICAL CHARACTERISTICS. In case of a SE DC-terminated input, the DC common mode voltage should match the average level of the applied reference clock signal.



PLL

The PLL contains a phase frequency detector, a charge pump, an on-chip integrator with an additional off-chip filter connected to pin fltr, and three selectable LC-tank VCOs with different central frequencies. The recommended parameters of the external filter schematic components shown in Fig. 2 are for reference only, and can be modified based on specific requirements.

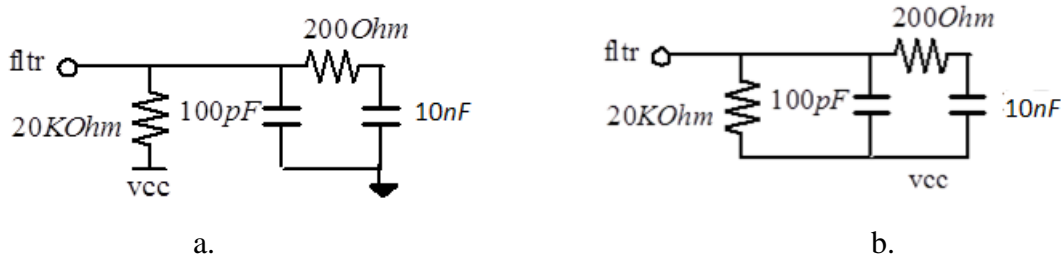


Fig. 2. External Filter Schematic for Positive (a) and Negative (b) Power Supplies

The main function of the PLL is to synthesize a full-rate clock **C** by aligning the phase and frequency of the divided clock **C16** from the internal divider to the externally applied reference clock **crp/crn**. The divided clock is delivered to outputs **c16p/c16n** through a CML output buffer **LS COB**. Selection of the required VCO is defined by the CMOS control signals **vc0** and **vc1** as shown in Table 1. The same signals are used to activate the **LS COB** block. Here “nc” means “not connected”.

Table 1. VCO and LS COB Control Modes

vc0	vc1	Selected VCO	LS COB
“0”	“0”	VCO1 (lower frequency)	On
“0”	nc	VCO1 (lower frequency)	Off
“0”	”1”	VCO2 (medium frequency)	On
nc	“0”	VCO3 (higher frequency)	Off
nc	nc	VCO1 (lower frequency)	Off
nc	”1”	VCO2 (medium frequency)	Off
”1”	“0”	VCO3 (higher frequency)	On
”1”	nc	VCO3 (higher frequency)	Off
”1”	”1”	VCO2 (medium frequency)	On

The PLL can also operate in open-loop mode with an external control voltage applied to pin **fltr**. In this case, the unused VCO is completely disabled in order to save power. The allowed control range is shown in Table 2.

Table 2. VCO Control Voltage

fltr voltage, V	Frequency of the active VCO
vcc	min
vcc-2.5	max



HS COB

The High Speed Clock Output Buffer (HS COB) receives a full-rate clock **C** from the PLL and converts it into CML output signal **cp/cn**. The buffer provides an internal single-ended termination of 50Ω to **vcc** for each output line and also requires 50Ω external termination resistors to be connected between **vcc** and each output.

LS COB

The Low-Speed Clock Output Buffer (COB) receives the divided-by-16 clock signal from the PLL's divider and converts it into LVDS output signal **c16p/c16n**. The proprietary low-power LVDS output buffer utilizes a special architecture that ensures operation at frequencies up to 2.5GHz with low power consumption. The buffer satisfies all requirements of the IEEE Std. 1596.3-1996 and ANSI/TIA/EIA-644-1995. For correct operation, it requires external differential 100Ω DC termination at the receiver side. The output pins should **NEVER** be **CONNECTED** to devices with 50Ω termination to ground **WITHOUT DC BLOCKS!**

The buffer can be enabled or disabled by the external 3-state control signals **vc0** and **vc1** as shown in Table 1 above.

POWER SUPPLY CONFIGURATION

The part can operate with either negative supply (**vcc** = 0.0V = ground and **vee** = -2.8V or -3.3V), or positive supply (**vcc** = $+2.8\text{V}$ or $+3.3\text{V}$ and **vee** = 0.0V = ground). In case of the positive supply, all CML I/Os need AC termination when connected to any devices with 50Ω termination to ground. Different PCB layouts will be needed for each different power supply combination.

All the characteristics detailed below assume vee = 0.0V and vcc = +3.3V.

ABSOLUTE MAXIMUM RATINGS

Caution: Exceeding the absolute maximum ratings shown in Table 3 may cause damage to this product and/or lead to reduced reliability. Functional performance is specified over the recommended operating conditions for power supply and temperature only. AC and DC device characteristics at or beyond the absolute maximum ratings are not assumed or implied. All min and max voltage limits are referenced to ground (assumed **vee**).

Table 3. Absolute Maximum Ratings

Parameter	Min	Max	Units
Supply Voltage (vcc)		3.6	V
Power Consumption		580	mW
Input Voltage Swing (SE)		1.0	V
Case Temperature		+90	°C
Storage Temperature	-40	+100	°C
Operational Humidity	10	98	%
Storage Humidity	10	98	%



TERMINAL FUNCTIONS

TERMINAL			DESCRIPTION
Name	No.	Type	
High-Speed I/Os			
cp	3	Output	CML differential clock outputs with internal SE 50 Ω termination to VCC. Require external SE 50 Ω termination to VCC
cn	5		
Low-Speed I/Os			
crp	17	Input	LVDS/CML clock inputs. See LS CIB for allowed application schemes
crn	15		
c16p	23	Output	LVDS clock outputs. See LS COB for a detailed description
c16n	21		
Controls			
vc0	9	Input	3-state control signals
vc1	11		
fltr	19	Input	Pin for connecting the external loop filter. Can be also used for VCO external control in open-loop mode
Supply and Termination Voltages			
Name	Description		Pin Number
vcc	Positive power supply (+2.8V or +3.3V)		2, 4, 6, 8, 10, 12, 14, 16, 18, 20, 22, 24
vee	External ground (0V)		1, 7, 13



ELECTRICAL CHARACTERISTICS

PARAMETER	MIN	TYP	MAX	UNIT	COMMENTS
General Parameters					
vee		0.0		V	External ground
vcc		2.8 / 3.3		V	±5%
Ivcc		160		mA	
Power consumption		450 / 530		mW	
Junction temperature	-25	50	125	°C	
LS Input Reference Clock (crp/crn)					
Frequency	1.50		2.006	GHz	1/16 of the VCO frequency
Swing	200		800	mV	Differential, p-p
CM Voltage Level	1.2		vcc-0.4	V	
HS Output Clock (cp/cn)					
Frequency	24.0		32.1	GHz	Matches VCO frequency
Logic "1" level		vcc		V	
Logic "0" level		vcc-0.55		V	
Jitter		200		fs	Peak-to-peak at 25.78GHz
Duty Cycle		50%			
Phase Noise		108		dBc/Hz	At 32GHz at 1.0MHz offset
LS Output Clock (c16p/c16n)					
Frequency	1.50		2.006	GHz	
Interface		LVDS			Meets the IEEE Std.
3-State control inputs (vc0, vc1)					
Logic "1" level		vcc-0.3		V	
"nc" level		(vcc+vee)/2			Recommended to keep not connected. The required level is created internally.
Logic "0" level		vee+0.3		V	
VCOs					
Low frequency of VCO1		24.0		GHz	Lower-frequency VCO
High frequency of VCO1		27.5		GHz	
Low frequency of VCO2		25.3		GHz	Medium-frequency VCO
High frequency of VCO2		27.7		GHz	
Low frequency of VCO3		27.5		GHz	Higher-frequency VCO
High frequency of VCO3		32.1		GHz	
External control voltage range	vcc-2.5		vcc	V	In open-loop mode

PACKAGE INFORMATION

The chip die is housed in a custom 24-pin CQFN package shown in Fig. 3. The package provides a center heat slug located on its back side to be used for heat dissipation. ADSANTEC recommends for this section to be soldered to the VCC plain, which is ground for a negative supply, or power for a positive supply.

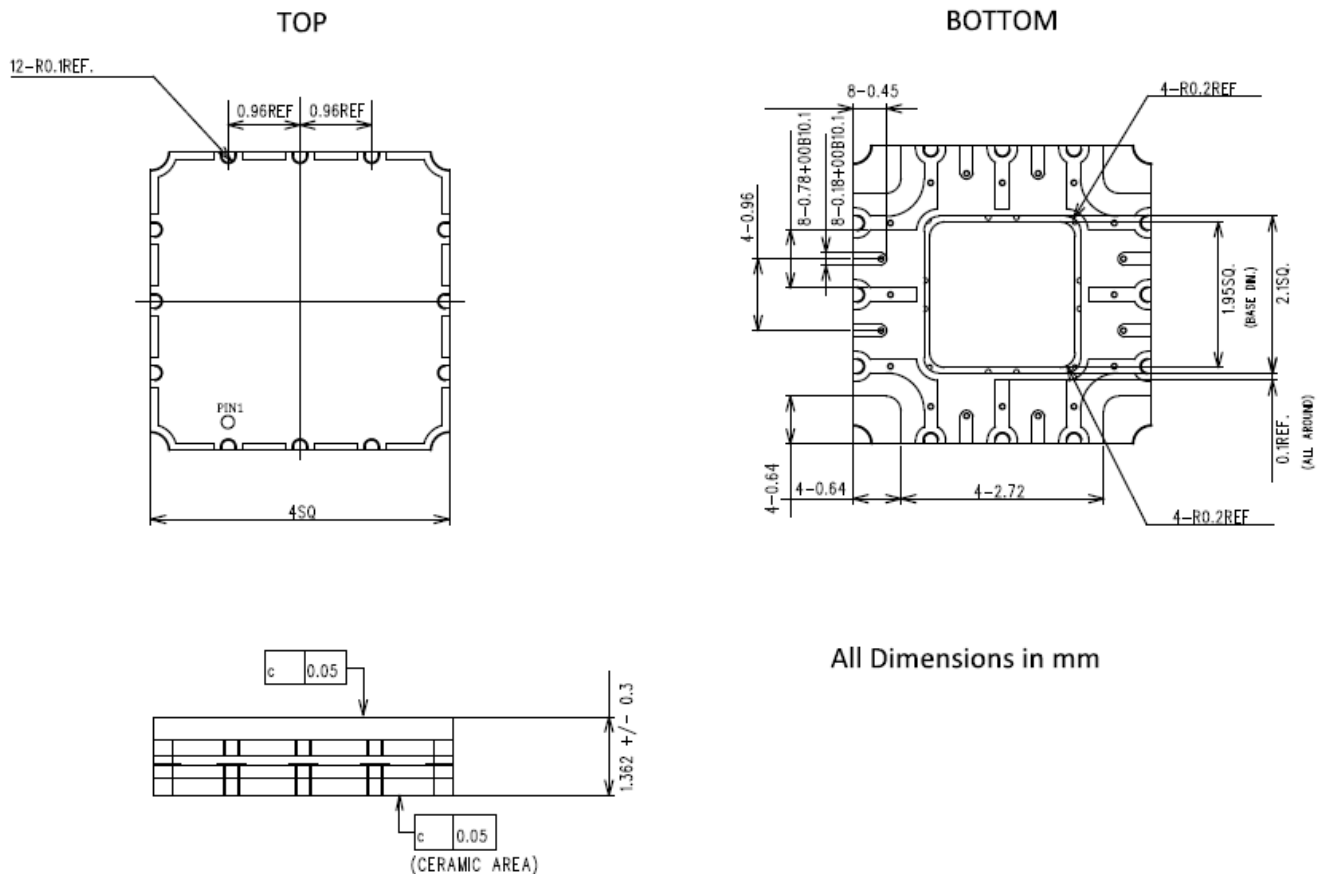


Fig. 3. CQFN 24-Pin Package Drawing (All Dimensions in mm)

The part's identification label is ASNT8151-KHC. The first 8 characters of the name before the dash identify the bare die including general circuit family, fabrication technology, specific circuit type, and part version while the 3 characters after the dash represent the package's manufacturer, type, and pin out count.

This device complies with Commission Delegated Directive (EU) 2015/863 of 4 June 2015 amending Annex II to Directive 2011/65/EU of the European Parliament and of the Council as regards the list of restricted substances (Text with EEA relevance) on the restriction of the use of certain hazardous substances in electrical and electronics equipment (RoHS Directive) in accordance with the definitions set forth in the directives for all ten substances.



REVISION HISTORY

Revision	Date	Changes
1.0.3	04-2023	Updated Package Drawing
1.0.2	04-2021	Initial release